Absorptive SPDT Solid State RF Switch

ZFSWA2-63DR+

The Big Deal

- Wide bandwidth 500 to 6000 MHz
- Very high isolation, 65 dB at 1GHz
- Very fast switching, 35ns
- Rugged case with internal hermetically sealed ceramic semi-conductor module



Pricing: \$69.95 (QTY 1-9)

Product Overview

The ZFSWA2-63DR+ is a great general purpose SPDT solid state absorptive RF switch. With its broad frequency range, fast 35 ns switching time and excellent RF performance, the ZFSWA2-63DR+ is an excellent choice for many applications. In addition to it's versatility within system block diagrams, the ZFSWA2-63DR+ is designed for easy integration into your prototype design applications.

Key Features

Feature	Advantages
Designed for any environment	The ZFSWA2-63DR+ is equipped with a rugged shielded case, a hermetically sealed internal device with a wide operating temperature range (-55°C to 100°C)
	Suitable for many environments and applications the ZFSWA2-63DR+ offers excellent performance and value
Integrated CMOS Driver	-Operates from 3-5V -Low control current 5 µA allows compatibility with a variety of driver circuits -Internal Decoupling -Fast 35 ns Switching time
Excellent for a Variety of Applications From Bench to Integrated Systems	-High speed testers -Automated switching networks -Wireless Infrastructure -Military
Excellent RF Performance	-Wide bandwidth: 500 to 6000 MHz -Low Insertion Loss: 1.4 dB Typ -Low Supply current: 18 μA Typ -High Isolation: 65 dB Typ @ 1 GHz

Notes

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SPDT RF Switch

50Ω 500-6000 MHz

Absorptive RF Switch with Internal Driver Single Supply Voltage, +3V to +5V

Product Features

- Wide bandwidth, 500 to 6000 MHz
- High Isolation, 65 dB typ. at 1 GHz
- Low Insertion loss, 1.4 dB typ.
- Internal CMOS driver
- Fast switching, Rise/fall time, 25 ns typ.
- · Built rugged for tough environments
- Wide operating temperature, -55°C to 100°C

Typical Applications

- Cellular
- ISM, WCDMA, WIMAX
- PCN
- · Automated switching networks
- Military



ZFSWA2-63DR+

CASE STYLE: ZZ1322

Connectors	Model	Price	Qty.
SMA	ZFSWA2-63DR+	\$69.95 ea.	(1-9)
BRACKET	(OPTION "B")	\$5.00	(1+)

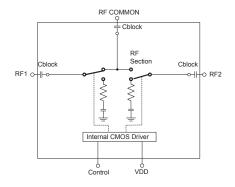
+RoHS Compliant

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

General Description

The ZFSWA2-63DR+ is a 50 Ω high isolation, absorptive SPDT RF switch designed for wireless applications, covering a broad frequency range from 500 to 6000 MHz with low insertion loss. The ZFSWA2-63DR+ operates on a single supply voltage in the range of +3V to +5V. This unit includes an internal CMOS driver. The switch consumes very low supply current, 18 µA typ. The ZFSWA2-63DR+ switch comes in a rugged built case for tough environments.

Schematic and Application Circuit



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BEV. B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.

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C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions, (collectively, "Standard Terms"); Purchasers of this part are entitled ZFSWA2-63DR+ to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.js/G/CP/AM 130703
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RF Electrical Specifications, 500 - 6000 MHz, T_{AMB}=25°C, V_{DD}= +3V to +5V

Parameter	Condition	Min.	Тур.	Max.	Units	
Frequency Range		500		6000	MHz	
	500 MHz		1.0	1.3		
	1000 MHz		1.15	1.5		
Insertion Loss	2000 MHz		1.4	1.7	dB	
	4000 MHz		1.7	2.1		
	6000 MHz		2.0	2.4		
Isolation between Common port and RF1/RF2 Ports	500 to 2000 MHz 2000 to 4000 MHz	55 48	65 57		dB	
isolation between Common port and hr 1/hrz Ports	4000 to 6000 MHz	35	45		ub	
	500 to 2000 MHz	50	60			
Isolation between RF1 and RF2 ports	2000 to 4000 MHz	43	50		dB	
·	4000 to 6000 MHz	35	45			
	500 to 2000 MHz		20			
Return Loss (ON STATE)	2000 to 4000 MHz		17		dB	
	4000 to 6000 MHz		15			
D	500 to 2000 MHz		13			
Return Loss @ RF1/RF2 ports (OFF STATE)	2000 to 4000 MHz		13 13		dB	
	4000 to 6000 MHz V _{DD} =3V, 500 to 2000 MHz		47			
	2000 to 6000 MHz		40			
Input IP3	V _{DD} =5V, 500 to 2000 MHz		49		dBm	
	2000 to 6000 MHz		44			
	V _{DD} =3V, 500 to 2000 MHz		24			
Input 1dB Compression (1)	2000 to 6000 MHz		24		dBm	
	2000 to 6000 MHz		27			
ı	DC Electrical Specifications	5				
VDD, Supply Voltage		3		5	V	
Supply Current (2)	V _{DD} =5V		18		μΑ	
Control Voltage Low		0		0.5	V	
Control Voltage High (3)		2.7		V _{DD}	V	
Control Current			5		μΑ	
	Switching Specifications					
Rise/Fall Time (10 to 90% or 90 to 10% RF)	V _{DD} =5V		25		nSec	
Switching Time (50% CTRL to 90/10% RF)	V _{DD} =5V		35		nSec	
Video Feed through (Control 0-5V, Frequency 1 MHz)	V _{DD} =5V		30		mV _{P-P}	

Notes:

- 1. Note absolute maximum rating for input and dissipated power. At 5V, over 2000-6000 MHz, 0.2 dB compression.
- 2. Increases with switching repetition rate. See graph.
- 3. CMOS interface latch-up condition may occur when logic high signal is applied prior to power supply.

Absolute Maximum Ratings

Parameter	Ratings
Operating Temperature	-55°C to 100°C
Storage Temperature	-55°C to 100°C
V _{DD} , Supply Voltage	2.7 to 5.5V
Voltage Control	-0.2V Min. V _{DD} Max.
RF input power	1Watt
Dissipated Power at 25°C	370mW
ESD, HBM	Class 1A (250 to <500V) per JESD22-A114
ESD, MM	Class A (passes 50V) per JESD22-A115
ESD, CDM	Class III (500 to <1000V) per JESD22-C101

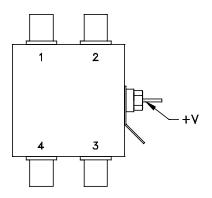
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Truth Table (State of control voltage selects the desired switch state)

State of Control Voltage	Switch State - RF Common to		
State of Control Voltage	RF1	RF2	
Low	ON	OFF	
High	OFF	ON	

ON- low insertion loss state **OFF- Isolation State**

Coaxial Configuration

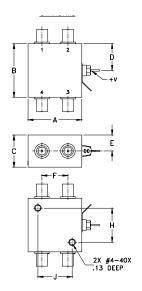


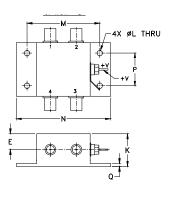
Coaxial Connections

Function	Port Number	Description
RF COM	1	RF Common/ SUM Port
RF1	4	RF Out #1/In Port #1
RF2	3	RF Out #2/In Port #2
Control	2	CMOS Control IN
VDD	V+	Supply Voltage
GND	Case	RF Ground

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Outline Drawing (ZZ1322)





Outline Dimensions (inch)

В С D Ε Н Κ O J L M Ν 1.25 1.25 0.75 0.63 0.38 0.6 -- 0.800 0.800 0.76 0.125 1.688 2.18 0.75 0.07 grams 31.75 31.75 19.05 16.00 9.65 15.24 -- 20.32 20.32 19.30 3.18 42.88 55.37 19.05

Additional Detailed Technical Information

Additional information is available on our web site. To access this information enter the model number on our web site home page.

Performance data, graphs

Case Style: ZZ1322

Environmental Ratings: ENV28

Pricing & Availability Information

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